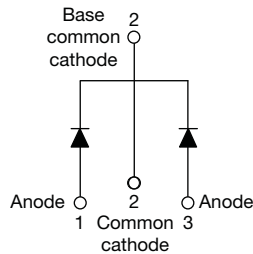




High Performance Generation 5.0 Schottky Rectifier, 2 x 8 A



TO-220AB



FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V_F vs. I_R trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47



RoHS COMPLIANT

PRODUCT SUMMARY	
Package	TO-220AB
$I_{F(AV)}$	2 x 8 A
V_R	100 V
V_F at I_F	0.58 V
I_{RM} max.	4 mA at 125 °C
T_J max.	175 °C
Diode variation	Common cathode
E_{AS}	36 mJ

APPLICATIONS

- High efficiency SMPS
- Automotive
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		100	V
V_F	8 Apk, $T_J = 125$ °C (typical, per leg)	0.55	
T_J	Range	- 55 to 175	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-16CTT100	UNITS
Maximum DC reverse voltage	V_R	$T_J = 25$ °C	100	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current per leg per device	$I_{F(AV)}$	50 % duty cycle at $T_C = 163$ °C, rectangular waveform		8	A
				16	
Maximum peak one cycle non-repetitive surge current per leg	I_{FSM}	5 μ s sine or 3 μ s rect. pulse	Following any rated load condition and with rated V_{RRM} applied	850	
		10 ms sine or 6 ms rect. pulse		210	
Non-repetitive avalanche energy per leg	E_{AS}	$T_J = 25$ °C, $I_{AS} = 1.5$ A, $L = 60$ mH		67	mJ
Repetitive avalanche current per leg	I_{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. I_{AS} at T_J max. as a function of time pulse See fig. 8		I_{AS} at T_J max.	A



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS	
Forward voltage drop per leg	$V_{FM}^{(1)}$	8 A	$T_J = 25\text{ }^\circ\text{C}$	-	0.72	V
		16 A		-	0.85	
		8 A	$T_J = 125\text{ }^\circ\text{C}$	-	0.58	
		16 A		-	0.69	
Reverse leakage current per leg	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	-	65	μA
		$T_J = 125\text{ }^\circ\text{C}$		-	4	mA
Junction capacitance per leg	C_T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C	520	-	pF	
Series inductance per leg	L_S	Measured lead to lead 5 mm from package body	8.0	-	nH	
Maximum voltage rate of change	dV/dt	Rated V_R	-	10 000	V/ μs	

Note

(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 55 to 175	$^\circ\text{C}$
Maximum thermal resistance, junction to case per leg	R_{thJC}	DC operation	2	$^\circ\text{C/W}$
Maximum thermal resistance, junction to case per device			1	
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-220AB (JEDEC)	16CTT100	

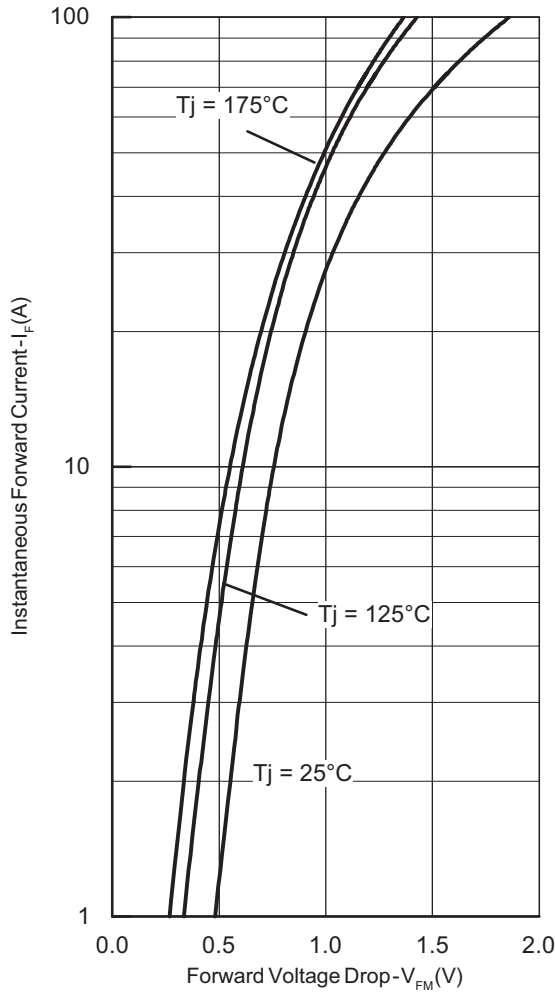


Fig. 1 - Maximum Forward Voltage Drop Characteristics

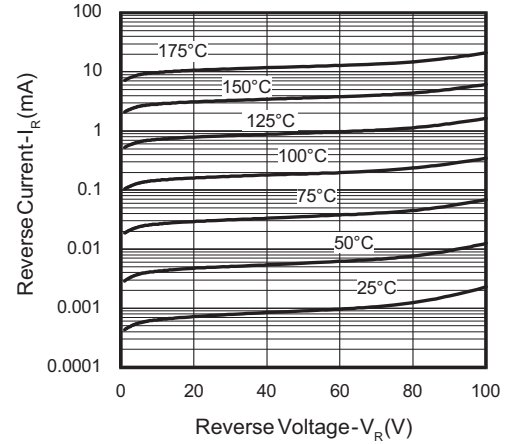


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

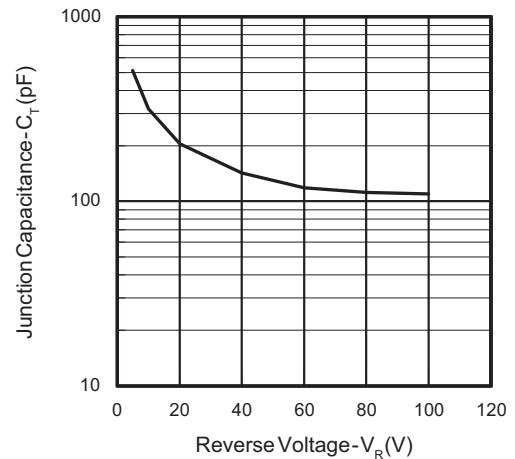


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

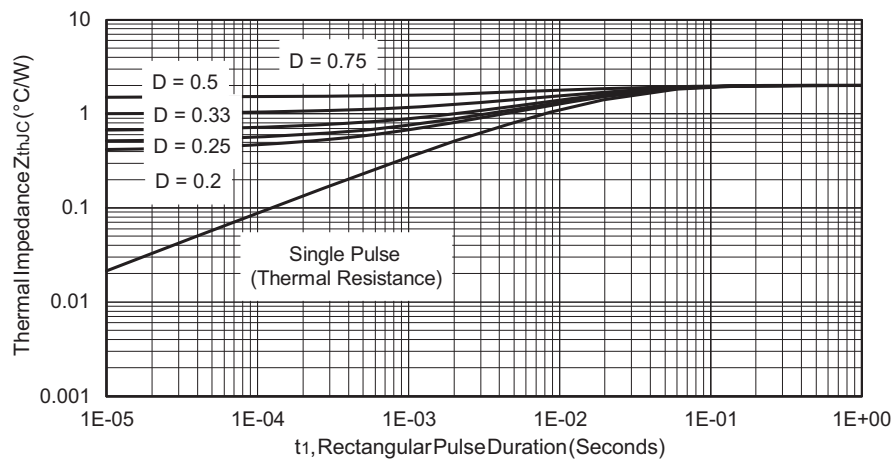


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

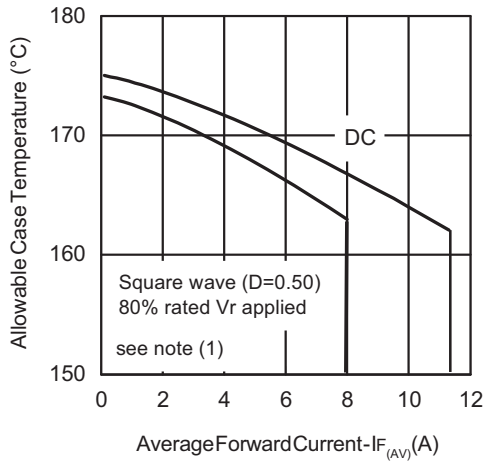


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

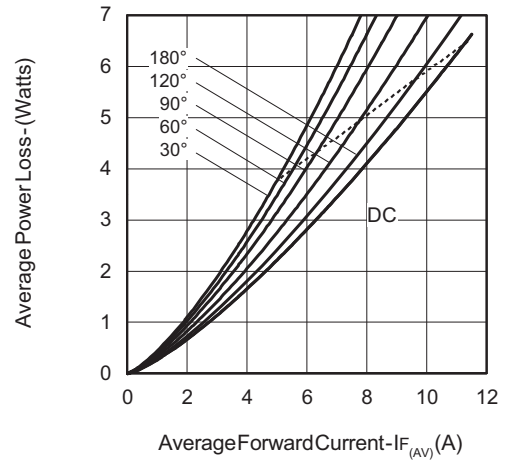


Fig. 6 - Forward Power Loss Characteristics

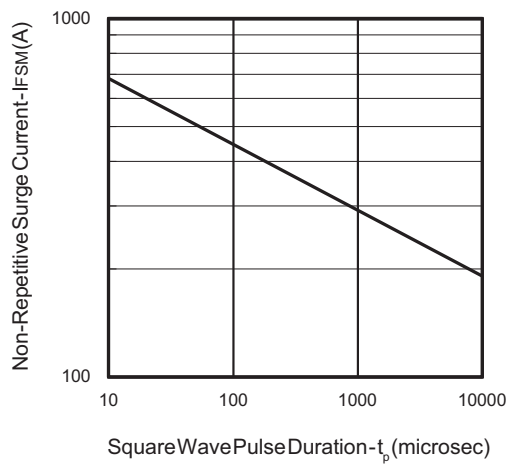


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

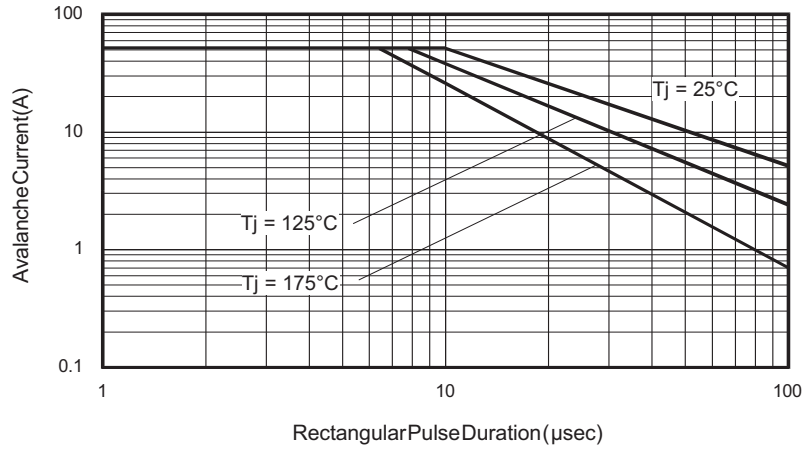


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

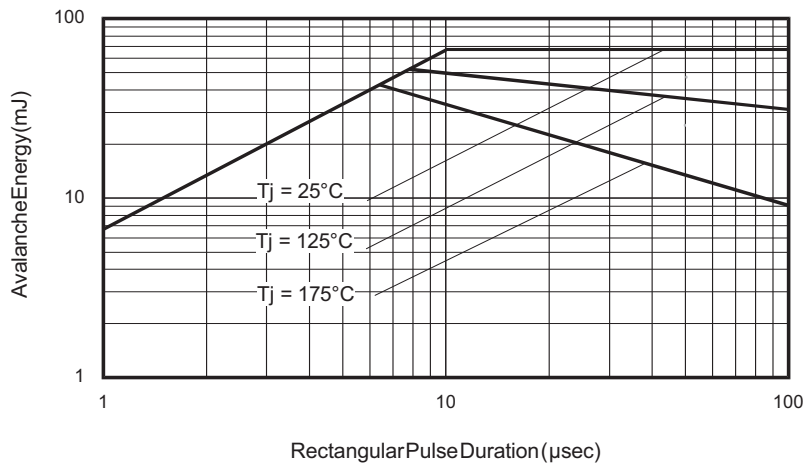
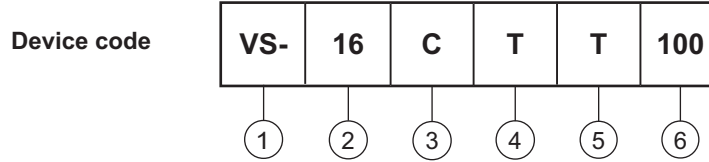


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)



ORDERING INFORMATION TABLE



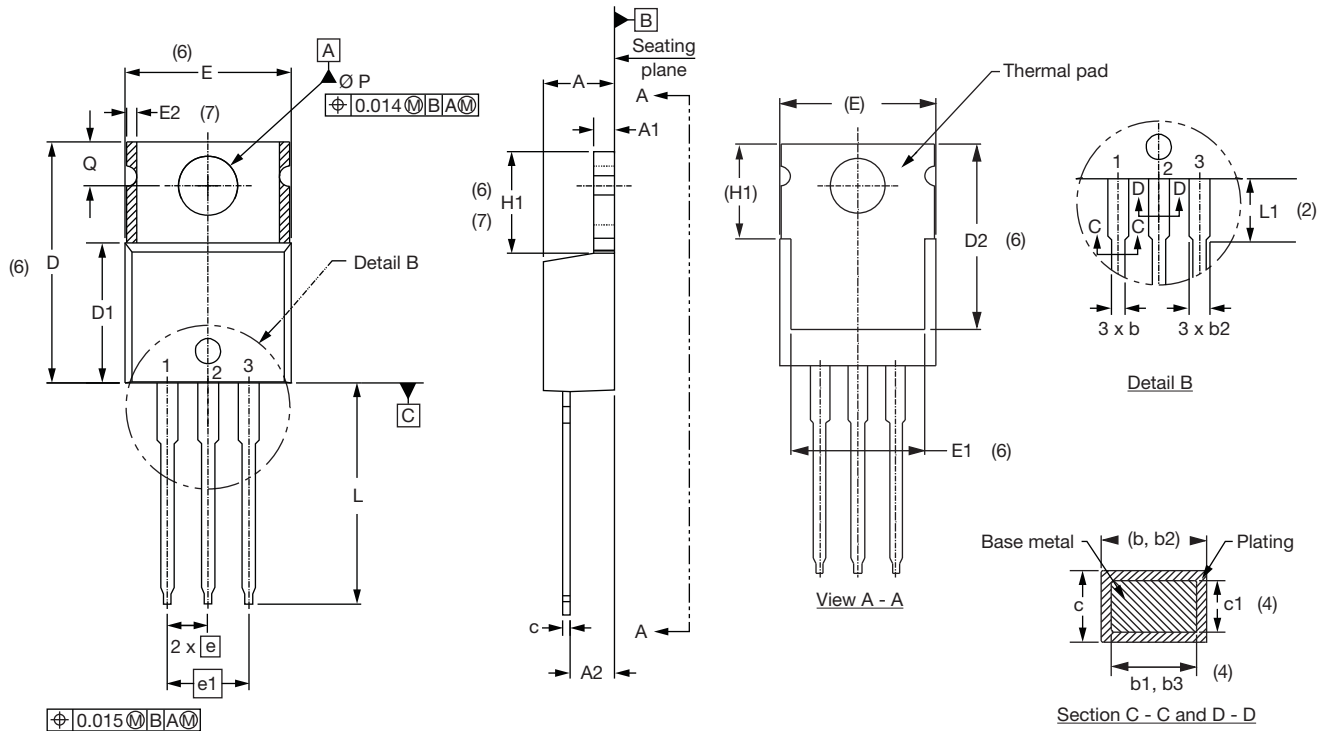
- 1** - Vishay Semiconductors product
- 2** - Current rating (16 A)
- 3** - Circuit configuration:
C = Common cathode
- 4** - Package:
T = TO-220
- 5** - T = Trench
- 6** - Voltage code (100 V)

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95222
Part marking information	www.vishay.com/doc?95225
SPICE model	www.vishay.com/doc?95229

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

1. - Anode/open
2. - Cathode
3. - Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
c	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
$\varnothing P$	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° to 93°		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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